





25V NPN LOW SATURATION TRANSISTOR IN SOT23

Features

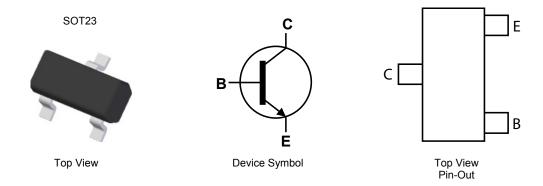
- BV_{CEO} > 25V
- BV_{CBO} > 35V forward blocking voltage
- I_C = 3A high Continuous Collector Current
- Low saturation voltage, V_{CE(SAT)} < 120mV @1A
- $R_{CE(SAT)}$ = 77mΩ for a low equivalent On-Resistance
- 725mW Power dissipation
- h_{FE} specified up to 6A for high current gain hold up
- Complementary PNP Type: ZXTP749F
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (§3)
- Weight 0.008 grams (approximate)

Applications

- MOSFET gate drivers
- Power switching in automotive and industrial applications
- · Motor drive and control



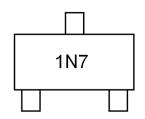
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN649FTA	1N7	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com.

Marking Information



1N7 = Product type Marking Code



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	35	V
Collector-Emitter Voltage	V _{CEO}	25	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	I _C	3	Α
Peak Pulse Current	I _{CM}	6	Α
Base Current	lΒ	500	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Power Dissipation	(Note 5)	P_{D}	725	mW
Thermal Resistance, Junction to Ambient (Note 5)		$R_{\theta JA}$	172	°C/W
Thermal Resistance, Junction to Leads (Note 6)		$R_{ heta JL}$	79	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C	

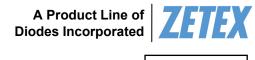
ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	≥ 8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

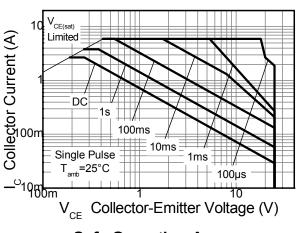
Notes:

^{5.} For a device surface mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
6. Thermal resistance from junction to solder-point (at the end of collector lead).
7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

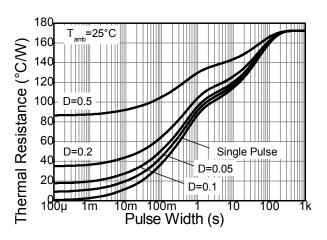




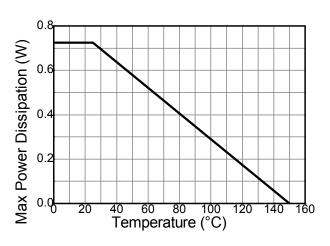
Thermal Characteristics and Derating information



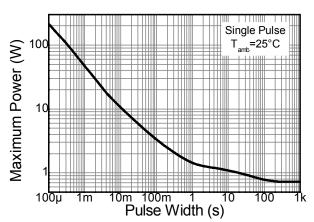
Safe Operating Area



Transient Thermal Impedance



Derating Curve



Pulse Power Dissipation





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

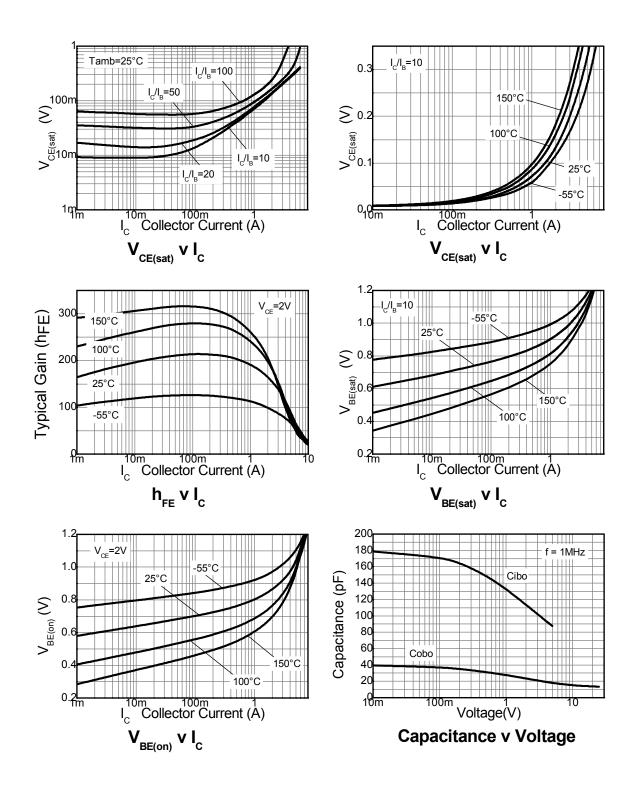
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	35	110	-	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 8)	BV _{CEO}	25	35	-	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.1	-	V	I _E = 100μA
Collector Cut-off Current	I _{CBO}	-	<1	50 0.5	nΑ μΑ	V _{CB} = 28V V _{CB} = 28V, T _A = +100°C
Emitter Cut-off Current	I _{EBO}	-	<1	50	nA	V _{EB} = 5.6V
Static Forward Current Transfer Ratio (Note 8)	h _{FE}	200 175 155 50	320 280 250 85	500 - - -	ı	$I_C = 100 \text{mA}, V_{CE} = 2V$ $I_C = 1A, V_{CE} = 2V$ $I_C = 2A, V_{CE} = 2V$ $I_C = 6A, V_{CE} = 2V$
Collector-Emitter Saturation Voltage (Note 8)	$V_{\text{CE(sat)}}$		70 200	120 300	mV	I _C = 1A, I _B = 100mA I _C = 3A, I _B = 300mA
Base-Emitter Saturation Voltage (Note 8)	V _{BE(sat)}	-	900	1000	mV	I _C = 1A, I _B = 100mA
Base-Emitter Saturation Voltage (Note 8)	V _{BE(on)}	-	780	850	mV	I _C = 1A, V _{CE} = 2V

Notes: 8. Measured under pulsed conditions. Pulse width $\leq 300 \mu s$. Duty cycle $\leq 2\%$





Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

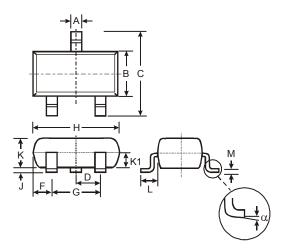






Package Outline Dimensions

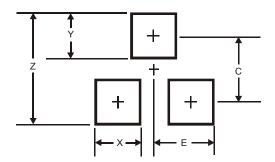
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.903	1.10	1.00		
K1	-	1	0.400		
L	0.45	0.61	0.55		
М	0.085	0.18	0.11		
α	0°	8°	-		
All	All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Υ	0.9
С	2.0
E	1.35





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